

Application Note: SQ33068 6V to 75V Synchronous Buck Controller With Wide Duty Cycle Range

Advanced Design Specification

General Description

The SQ33068 is 75V synchronous buck controller with type Ⅲ voltage mode control and feedforward. Minimum tens of nanosecond on-time facilitates large step-down ratios. The SQ33068 continues to operate when input voltage decreases to as low as 6V.

VIN pin voltage determines whether SQ33068 enters DEM to prevent reverse charging. Cycle-by-cycle over current protection is accomplished by measuring the voltage across the low-side MOSFET or current sense resistor. Forced-PWM (FPWM) eliminates frequency variation and a selectable diode emulation lowers power consumption at light-load conditions. The switching frequency as high as 1 MHz can be set or synchronized to an external clock.

Ordering Information

Features

- 6V to 75V Input Voltage Range
- 0.8V to 60V Output Voltage Range
- Switching Frequency: 100kHz~1MHz – SYNC In/Out Capability
- Soft-Start or Voltage Tracking
- 0.8V±1% Reference Voltage
- Minimum On-Time: 60ns typical
- Minimum Off-Time: 240ns typical
- Type III Voltage-Mode Control with Feedforward al
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with Feedforward
mplifier
- High Gain-Bandwidth Error Amplifier
- Open-Drain Power Good Indicator
- Protection Features
	- Cycle-by-cycle Over current Protection
	- Prevent Reverse Charging Protection
	- Input UVLO with Hysteresis
	- VCC and BST UVLO Protection
	- Thermal Shutdown Protection with **Hysteresis**
	- Compact Package: QFN3.5x4.5-20

Applications

Telecom Power Application

- RF Power Application
- Commercial Drone Application

Typical Application

Pinout (Top View)

Top mark: **GQY***xyz* (Device code: **GQY**, *x=year code, y=week code, z= lot number code***) FOT Smax**

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Absolute Maximum Ratings

Recommended Operating Conditions (Note 3)

Block Diagram

Electrical Characteristics

(VIN=48V, VEN/UVLO=1.5V, RRT=25kΩ, Tj=25˚C, Minimum and maximum limits apply over the –40°C to 125°C junction temperature range, unless otherwise specified)

Note 1: Stresses beyond the listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may remain possibility to affect device reliability.

Note 2: θJA is measured in the natural convection at $T_A = 25^\circ$ C on a high effective four-layer PCB with thermal via according with JESD 51-2, -5, -7, -8, -14 measurement standard.

Note 3: The device is not guaranteed to function outside its operating conditions.

Operation Principles

Input Voltage

SQ33068 adopts wide range input voltage, varying from 6V to 75V. It also samples V_{in} value to realize V_{in} feedforward to remove Vin impact on voltage loop compensation.

A resistor R_{VIN} (2.2 Ω) and a capacitor C_{VIN} (100nF) is recommended to added on Vin pin to filter the noise, as shown in Fig 3.

Fig 3. Vin Pin Connection

Power Supply VCC

In SQ33068, a LDO is connected to V_{in} to generate VCC voltage, providing internal logic power and gate driver power. If V_{in} >7.5V, output of LDO (VCC) is 7.5V. If Vin<7.5V, VCC will follow Vin with a small voltage drop. The maximum LDO (VCC) current ability is 50mA and it can support high power application.

Usually a 2.2uF capacitor is needed to connect VCC and PGND.

There is large power loss, $(V_{in} - 7.5)^*V_{VCC}$, on LDO if V_{in} is larger than VCC (7.5V) too much. Thus, VCC can be connected to output voltage or auxiliary voltage (8V~13V), using a diode to decrease power loss on SQ33068, as shown in Fig 4. If SQ33068 detects VCC is higher than 8V, it will turn off internal LDO to decrease power loss on it. Under this condition, a diode is also needed to avoid reverse current if $V_{in} < V_{AUX}$ or Vout.

Prevent Reverse Charging Protection(VIN DEM)

In FPWM Buck, if load is light, under load transient or prebias start, the energy stored in the large output capacitor may flow back to input capacitor and the input voltage increases to a high level, which may damage Vin pin. So, in SQ33068, if input voltage is larger than VIN

DEM, the device will enter diode emulation mode to stop energy flowing back to input capacitor.

EN Resistor Setting

SQ33068 can set programmable EN/UVLO voltage with user-defined hysteresis.

When EN pin is higher than 0.4V and lower than 1.2V, SO33068 enters standby mode. Under standby mode, internal LDO is working and SS/TRK pin is pull down to zero with no switching. When EN pin is higher than V_{EN_on}=1.2V, SQ33068 is in normal operation mode and a I_{EN_HYS} =10uA current flows out of EN pin to generate Hysteresis off voltage. der standby model
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EX pun to general

 R_{EN1} &R_{EN2} are used to set EN/UVLO voltage. V_{in_on} is SQ33068 working V_{in} pin voltage and V_{in_off} is stopping working voltage. Use equation:

 R_{EN1} & R_{EN2} can be calculated.

Fig 5. Programmable EN Set

In some application, a remote signal is used to control SQ33068. In this application, a resistor R₁(100 Ω) is recommended to added on EN pin to avoid voltage spike caused by L_{line}.

Fig 6. Remote Control Circuit

Frequency setting

A resistor is must needed on RT pin to set internal basic operation frequency, f_{RT} , as shown in Fig 7. The switching frequency range is from 100 kHz to 1 MHz.

Fig 7. Frequency Set

The switching frequency, *f*s, can be calculated by equation below:

$$
f_{\rm s}(\text{kHz}) = f_{\rm RT}(\text{kHz}) = \frac{10^3}{0.093 \text{R}_{\rm RT}(\text{k}\Omega) + 0.14}
$$

Synchronization and FPWM&Diode Emulation Mode (DEM) Selection

SQ33068 can implement synchronization by SYNCIN pin. The external clock signal added on SYNCIN pin should satisfy requirements below:

Frequency range: 100 kHz~1MHz,

 -20% $f_{RT} \sim +50\%$ f_{RT}

Maximum voltage amplitude: 13V

Minimum pulse width: 50ns

SYNCIN pin can also be used to select FPWM&Diode emulation mode.

If SYNCIN is higher than 2V, it operates under FPWM, or named CCM (continuous conduction mode). The IC also operates under FPWM if synchronization is used. Take internal resistor R_{SYNCIN} into consideration to make sure high-level voltage of SYNCIN is larger than 2V if divided resistor is used here.

When SYNCIN is connected to GND, it selects diode emulation mode. In this mode, SQ33068 operates under DCM (discontinuous conduction mode) at light loads while SQ33068 still operates under CCM at heavy loads.

When SQ33068 operates under diode emulation mode, LX will use zero crossing detection to determine if LO should be turn off.

Under light load or no-load condition, the power loss will decrease if SQ33068 works under DCM, however the light load transient will be slower.

DCM is also applied during start-up to prevent reverse current, whatever SYNCIN is high or low voltage. Finally, DCM changes to CCM gradually if SYNCIN is high level or it operates under synchronization.

Soft Start&Tracking Function

When EN pin is above 1.2V, a 10uA current flows out of SS/TRK pin to charge external capacitor. This can control amplifier's reference voltage to program soft start time. The \overline{C}_{ss} can be set by using the equation:

$$
C_{SS} = \frac{t_{ss}I_{ss}}{V_{_{REF}}}
$$

 t_{SS} is set soft start time, $I_{SS}=10uA$, $V_{REF}=0.8V$.

Recommended C_{SS} capacitance is 200nF under 200kHz switching frequency.

Fig 10. Tracking and PGOOD Function Waveform

Customers can also connect a signal to SS/TRK pin to let output voltage track the added control signal. The typical waveform of V_{out}, SS/TRK, PGOOD is shown in Fig 10.

The control signal can be divided output voltage of master or a voltage source. The circuit of two tracking configurations following a master is shown in Fig 11.

Fig 11. Tracking Function Circuit

PGOOD Indicator

PGOOD pin is used to reflect output voltage state, by detecting FB voltage as shown in Fig 10. When the FB voltage exceeds 94% V_{REF}, with 2% hysteresis, the switch S_{PGOOD} turns off and when the FB voltage exceeds 108% V_{REF}, the switch S_{PGOOD} turns on, pulling PGOOD low, with 3% hysteresis. The switch S_{PGOOD} turn on or turn off delay time is 33 μs.

PGOOD pin can be used as shown in Fig 12. PGOOD pin should be connected to a resistor, $10kΩ~100kΩ$, and pull up to a DC voltage, usually VCC pin. When PGOOD is pull up to the DC voltage, it means output has been established. Then, PGOOD can be connected to next system to indicator if V_{out} has been established.

Fig 12. PGOOD Controlling EN/UVLO

Type-III Voltage Mode Control (COMP&FB)

SQ33068 adopts voltage-mode control, Type-III circuit, compensation with feed-forward, $k_{FF}=15$ V/V. It has two zeros and three poles to compensate zeros and poles caused by the systems. COMP pin is output of error amplifier, of which gain and bandwidth are both extremely large. FB pin is output voltage feed back pin, connected to negative input of the amplifier. The positive input of the amplifier is precise 800mV reference voltage. The detailed design method will be presented later.

Gate Driver

SQ33068 has 2.3A source current and 3.5A sink current, so it can be used in large current application, where Q_g is large or even two MOSFETs are used in parallel. The large current ability means fast turn on&turn off speed and switching loss can be reduced.

The maximum voltage of LO is VCC voltage and VCC supplies the LO power.

If Q_g of total high side (or low side) MOSFET is large than $60nC$ ($@Vgs=10V$) or external gate driver resistor is added, please evaluate the deadtime, efficiency and heat carefully.

Bootstrap Circuit

VCC also charges an external 0.1uF BST-LX capacitor which supplies HO power, through external bootstrap heat carefully.
 Bootstrap Circuit

VCC also charges an external 0.1uF BST-LX capacitor

which supplies HO power, through external bootstrap

diode (ultra-fast recovery diode is recommended). Thus,

the maximum veltage o the maximum voltage of HO is NCC minus $V_{BST-FWD}$ and V_{BST-FWD} is bootstrap diode voltage drop.

Programmable OCP

SQ33068 can set programmable OCP as circuit below. In Fig 13(a), voltage drop on R_{dson} is sampled, without any extra power loss, while in Fig 13(b), a sampling resistor is needed and voltage across it is sampled. SQ33068 compares the ILIM pin voltage with internal reference each duty cycle to determine if I_L exceeds set OCP threshold.

Fig 13(a). Programmable OCP Rds_on Mode

Fig 13(b). Programmable OCP Rsense Mode

Under different implementations, OCP current I_{ILM} through ILIM pin is different. I_{LIM_Rds_on}=200uA @25°C,

which incorporates a TC of $+2700$ ppm/ $\mathrm{^{\circ}C}$, in Fig 13(a) $R_{ds \text{ on}}$ mode and $I_{\text{LIM RS}}=100uA$ and it will not change $@-40\degree C~125\degree C$ in Fig 13(b) R_{sense} mode. A resistor R_{ILIM} is connected between ILIM pin and sampling point.

The R_{ILIM} can be set as equation below:
\n
$$
R_{ILIM} = \begin{cases}\n\frac{(I_{OUT_OCP} - \Delta I_L / 2)R_{ds_on} Q_2}{I_{LM_Rds_on}}, & R_{ds_on} \text{ mode} \\
\frac{(I_{OUT_OCP} - \Delta I_L / 2)R_s}{I_{LM_RS}}, & R_{sense} \text{ mode}\n\end{cases}
$$

 I_{out_OCP} is usually equal to twice maximum rated I_{out} if there is no other user's requirement.

In order to avoid voltage ring impact, a capacitor C_{ILM} connected between ILIM to PGND is essential. Approximately 6 ns of $R_{ILIM} \cdot C_{ILIM}$ is recommended.

Fig 14 shows the OCP logic, CLAMP is internal signal which is used to limit large inductor current when output shorts, RAMP is PWM waveform. If the over current condition that OCP signal is high level when SQ33068 detects inductor current, lasts for 128 continuous clock cycles, OCP is triggered and SS is pulled low for 8192 clock cycles. Then SQ33068 enters auto recovery state.

Thermal Shutdown

SQ33068 monitors die temperature under normal operating mode. Once die temperature rises above internal OTP threshold, IC will stop switching. If die temperature is lower than hysteresis temperature, SQ33068 enters auto recovery state.

Power Stage Design Guide

Inductor calculation

Choose the inductance to provide the desired ripple current ΔI_L , between 30% and 40% of the maximum DC output current at nominal input voltage. The inductance is calculated as:

$$
L_{F} = \frac{(V_{in} - V_{out})V_{out}}{\Delta I_{L} f_{s} V_{in}}
$$

The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency. When SQ33068 operates under maximum or large duty, voltage drop on DCR of the inductor should be considered. Check the datasheet of the inductor whether its saturation current is higher than inductor peak current under OCP. ck the datasheet of
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Output Capacitors

Output capacitor C_{OUT} filters the inductor ripple current and stores the energy supplying to the load. Therefore, both steady state ripple and transient requirements must be taken into consideration when select the capacitor.

Capacitance is selected as equation below:

$$
C_{out} \geq \frac{\Delta I_{L}}{\Delta V_{out}^{2} - \left(R_{ESR} \Delta I_{L}\right)^{2}}
$$

$$
\sum_{out} \sum_{i} \frac{L_{F} \Delta I_{out}^{2}}{\left(V_{out} + \Delta V_{overshoot}\right)^{2} - V_{out}^{2}}
$$

Tantalum and electrolytic capacitors supply a large bulk capacitance to store energy while ceramic capacitors are usually added due to its low ESR to reduce the output voltage ripple.

Input Capacitors

Input capacitor C_{in} is necessary to reduce input voltage ripple. X5R or X7R ceramic capacitors are recommended to provide low input impedance. The input capacitance is calculated as below:

$$
C_{in} > \frac{D(1-D)I_{out}}{f_s(\Delta V_{in} - R_{ESR}I_{out})}
$$

Power MOSFET

MOSFET selection is important in DCDC converter design. The low R_{dson} of MOSFET can bring low conduction loss to achieve high efficiency. While low R_{dson} MOSFET has large Q_g , which leads to more switching loss. It is a trade-off to select suitable R_{dson} and Q_g . Low thermal resistance is also needed and it can make power loss result in low temperature. Besides, maximum current and voltage should be satisfied.

MOSFET power losses are calculated below, where suffixes 1 and 2 represent high-side and low-side MOSFET parameters, respectively.

1. Conduction loss

$$
P_{cond} = D(I_{out}^2 + \Delta I_L^2 / 12) R_{dson1} + (1-D) (I_{out}^2 + \Delta I_L^2 / 12) R_{dson2}
$$

2. Switching loss

$$
P_{sw}\!\!=\!V_{\text{inf}}\!f_s(I_{Lmin}t_r+I_{Lmax}t_f)/2
$$

 t_r and t_f are LX rising and falling time. Only high-side MOSFET switching loss is calculated and low-side MOSFET switching loss is negligible.

3. Gate driver loss

$$
P_{gate} = V_{CC}f_s(Q_{g1} + Q_{g2})
$$

The approximate calculation of gate driver loss is based on the MOSFET internal gate resistance, the added series gate resistance and the SQ33068 internal driver resistance.

4. Output charge loss

$$
P_{\rm coss}\!\!=\!\!f_{\rm s}\!(V_{in}Q_{\rm oss2}\!\!+\!E_{\rm oss1}\!\!-\!\!E_{\rm oss2})
$$

 E_{oss1} is the energy stored in C_{oss1} and dissipated at turn on, but this is offset by the stored energy E_{oss2} on C_{oss2} .

5. Body diode conduction loss

$$
P_{\text{diode_cond}}{=}\allowbreak V_{\text{F2}}\allowbreak f_s\allowbreak(I_{\text{Lmin}}t_{dt1}{+}\allowbreak I_{\text{Lmax}}t_{dt2})
$$

 V_{F2} is body diode conduction voltage. Only low-side MOSFET body diode conduction loss is calculated.

6. Body diode reverse recovery loss

PRR=Vin*f*sQRR2

QRR2 is low-side MOSFET body diode reverse recover charge.

Voltage Loop Design Guide

Control Loop Compensation Design

SQ33068 use voltage-mode control, Type-III circuit, with V_{in} feedback forward, where two zeros and three poles are used in compensation. The control circuit is shown below.

Fig 15. Control Loop Circuit

The two zeros are used to compensate LC resonance poles. The added poles and zeros are shown in picture below.

$$
G_{vd}(s) = \frac{V_{in}(1+\frac{s}{\omega_{ESR}})}{1+\frac{s}{Q_0\omega_0}+\frac{s^2}{\omega_0^2}}
$$

Where

$$
\begin{aligned} \varpi_0 &= \frac{1}{\sqrt{L_{\rm F}C_{\rm out}}} \\ \varpi_{\rm ESR} &= \frac{1}{R_{\rm ESR}C_{\rm out}} \\ \varrho_0 &= \frac{R_{\rm o}}{\sqrt{L_{\rm F}/C_{\rm out}}} \end{aligned}
$$

Following compensation in control loop circuit, there is a PWM comparator. The amplitude of the PWM is V_{in}/k_{FF} , V_{in} feed forward, and finally, the stability has nothing with V_{in}. The transfer function of PWM comparator is shown below:

$$
G_{M}(s) = \frac{1}{V_{RAMP}} = \frac{k_{FF}}{V_{in}}
$$

The compensator transfer function is shown below:

$$
G_c(s) = K_{mid} \frac{(1 + \frac{\omega_{z1}}{s})(1 + \frac{s}{\omega_{z2}})}{(1 + \frac{s}{\omega_{p1}})(1 + \frac{s}{\omega_{p2}})}
$$

The small signal open loop response of buck converter is the product of power stage, compensator and PWM

comparator transfer functions:

\n
$$
T_{vd}(s) = G_{vd}(s)G_M(s)G_c(s)
$$
\n
$$
= K_{mid} \frac{(1 + \frac{\omega_{z1}}{s})(1 + \frac{s}{\omega_{z2}})}{(1 + \frac{s}{\omega_{p1}})(1 + \frac{s}{\omega_{p2}})} \frac{1 + \frac{s}{\omega_{ESR}}}{1 + \frac{s}{\omega_0 \omega_0} + \frac{s^2}{\omega_0^2}} k_{FF}
$$

In Fig 15, $R_{FB1} & R_{FB2}$ are divider resistor and they determine the desired V_{out}.

Here provides a simplified compensator parameters design method:

1. RFB1&RFB2 calculation:

 R_{FB2} is selected for $1k\Omega$ ~5k Ω and R_{FB1} can be calculated:

 $R_{FB1}=R_{FB2}(V_{out}/V_{REF}-1)$

2. Select
$$
\omega_c
$$
 and K_{mid} calculation

 ω_c is crossing radian frequency and usually:

$$
\omega_c=1/20\sim1/5\,\omega_s
$$

Kmid (mid-frequency gain) can be calculated approximatively:

 $K_{mid} = \omega_c/(\omega_0 k_{FF})$

k_{FF}=15 is SQ33068 feedforward parameter.

R² can be calculated:

$R_2=K_{mid}R_{FR1}$

3. $\omega_{z1} \& \omega_{z2}$ calculation

These zeros are needed to cancel the LC oscillation and their value can be selected as below:

$$
\omega_{z1} = 0.5 \omega_0, \omega_{z2} = \omega_0
$$

Usually output capacitor has serial parasitic resistor and a zero is located at RESRCout. A pole is needed here to reduce ESR impact. Final pole is usually located at $\omega/2(\omega_s=2\pi f_s)$ to restrain switching frequency influence:

$$
\omega_{\text{p1}} = \omega_{\text{ESR}}, \omega_{\text{p2}} = \omega_s/2
$$

4. Compensator resistor and capacitor calculation

Once poles and zeros' value are determined, in compensator, these poles and zeros are fabricated by the resistor and capacitors and can be calculated as below:

$$
C_2=1/\omega_{21}R_2, C_3=1/\omega_{p2}R_2
$$

C_1=1/\omega_{22}R_{FB1}, R_1=1/\omega_{p1}C_1

Referring to Fig 16, the phase margin, Φ_M , is the difference between the loop phase at ω_c and -180° . Usually, 50° to $70^{\circ} \Phi_M$ in design is considered ideal.

EMI Filter Design Guide

Fig 17. Buck EMI Filter

The EMI filter design steps are as follows:

1. Calculate the required attenuation of the EMI filter at the switching frequency Frement Pendant Pendan

$$
\text{Attn} = 20 \log(\frac{I_{\text{peak}} \cdot 1 \mu V}{\pi^2 \mathcal{K} C_{\text{in}}} \sin(\pi D_{\text{max}}) - V_{\text{max}}
$$

Vmax is the allowed $\frac{d}{dx}$ $\frac{d}{dx}$ noise level for the applicable EMI standard.

2. Input filter inductor L_N is usually selected between 1- 10μ H. It can be lower to reduce losses in a high current design; N

3. Calculate input filter capacitor CF

$$
C_F = \frac{1}{L_{IN}} \left(\frac{10^{\frac{|\text{Attn}|}{40}}}{2\pi f_s} \right)^2
$$

The output impedance of the EMI filter must be extremely small and the EMI filter does not affect the loop gain of the buck converter. The resonant frequency of the EMI filter is:

$$
f_{\rm res_filter} = \frac{1}{2\pi\sqrt{L_{\rm IN}C_{\rm F}}}
$$

R^D is used to reduce the peak output impedance at *f*res_filter to reduce EMI filter impact on loop gain of the buck converter. C_D blocks the DC component of the input voltage to avoid power loss in R_D . C_D should have lower impedance than R_D at $f_{\text{res_filter}}$ with a capacitance value greater than that of the input capacitor C_{IN} :

$$
C_{D} \geq 4C_{IN}
$$

Select the damping resistor R_D :

$$
R_{_{D}}=\sqrt{\frac{L_{_{IN}}}{C_{_{IN}}}}
$$

Layout Considerations

A proper PCB design must follow the below guidelines:

(a) To achieve a good EMI performance and to reduce the switching frequency voltage ripples, the output of the EMI rectifier should be connected to the C_{IN} capacitor first, then to the switching circuit.

(b) The inductor should be connected to the C_{OUT} capacitor first, and then to the load for a small output voltage ripples.

(c) The LX switching node being short, wide and small is benefit to EMI. The parasitic inductor here should be as small as possible to decrease LX peak ringing amplitude, which may be exceed maximum voltage stress of MOSFET. If the LX peak ringing amplitude is excessive, the snubber between LX and GND is needed.

(d) Input capacitors, output capacitors, inductors and MOSFETs are placed on the top side of the PCB for a good cooling environment.

(e) The circuit loop of all switching circuit should be kept as small as possible to decrease disturbance as shown in Fig. 18: High-side & Low-side power loop, High-side & Low-side driver circuit loop.

(f) C_{BST} and C_{VCC} should be as close as possible to the IC to minimize the loop. High-side & Low-side driver circuit loops are also should be small. Placing a 2ohm-10ohm resistor in series with C_{BST} to slows down highside MOSFET turn on speed can reduce the LX peak ringing amplitude.

(g) Small signal ground should be different part with power ground to avoid noise from power stage. COMP, FB, RT, SS/TRK, SYNCIN pin should be away from LX, BST, HO, LO pin to avoid disturbances. Use internal layer as ground plane if possible.

(h) The distance between LX and ILIM pin where ILIM resistor is set should be as close as possible.

(i) Connect the PGND pin to the system ground plane

using an array of vias under the exposed pad. Connect the PGND directly to the input and output capacitors.

IC Layout Reference

Fig 19. SQ33068 Layout Reference

QFN3.5×4.5 -20 Package Outline & PCB Layout Design

Taping & Reel Specification

1. QFN3.5×4.5-20 taping orientation

3. Others: NA